

AD7441/AD7451

FEATURES

- Fast Throughput Rate: 1 MSPS**
- Specified for V_{DD} of 2.7 V to 5.25 V**
- Low Power at Max Throughput Rate:**
 - 4 mW Max at 1 MSPS with $V_{DD} = 3$ V
 - 9.25 mW Max at 1 MSPS with $V_{DD} = 5$ V
- Pseudo Differential Analog Input**
- Wide Input Bandwidth:**
 - 70 dB SINAD at 100 kHz Input Frequency
- Flexible Power/Serial Clock Speed Management**
- No Pipeline Delays**
- High Speed Serial Interface—SPI®/QSPI™/
MICROWIRE™/DSP Compatible**
- Power-Down Mode: 1 μ A Max**
- 8-Lead SOT-23 and MSOP Packages**

APPLICATIONS

- Transducer Interface
- Battery-Powered Systems
- Data Acquisition Systems
- Portable Instrumentation
- Motor Control
- Communications

GENERAL DESCRIPTION

The AD7441/AD7451 are, respectively, 10-bit and 12-bit, high speed, low power, successive approximation (SAR) analog-to-digital converters that feature a pseudo differential analog input. These parts operate from a single 2.7 V to 5.25 V power supply and feature throughput rates up to 1 MSPS.

The parts contain a low noise, wide bandwidth, differential track-and-hold amplifier (T/H) that can handle input frequencies in excess of 1 MHz. The reference voltage for the AD7441/AD7451 is applied externally to the V_{REF} pin and can range from 100 mV to 3.5 V, depending on the power supply and what suits the application.

The conversion process and data acquisition are controlled using \overline{CS} and the serial clock, allowing the device to interface with microprocessors or DSPs. The input signals are sampled on the falling edge of \overline{CS} ; the conversion is also initiated at this point.

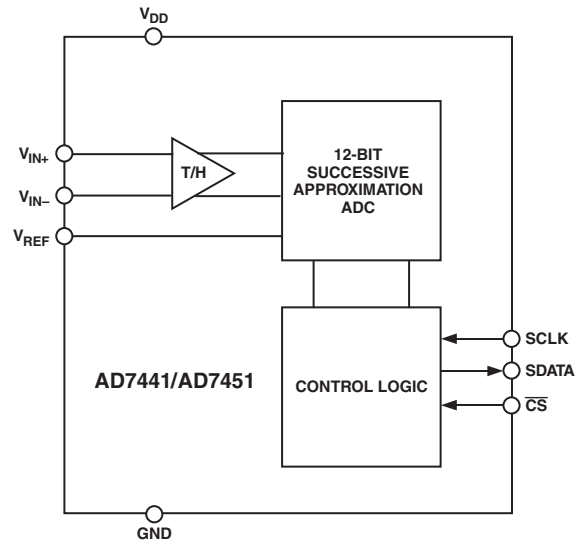
The SAR architecture of these parts ensures that there are no pipeline delays.

The AD7441/AD7451 use advanced design techniques to achieve very low power dissipation at high throughput rates.

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FUNCTIONAL BLOCK DIAGRAM



PRODUCT HIGHLIGHTS

1. Operation with 2.7 V to 5.25 V Power Supplies.
2. High Throughput with Low Power Consumption.
With a 3 V supply, the AD7441/AD7451 offer 4 mW max power consumption for a 1 MSPS throughput rate.
3. Pseudo differential Analog Input.
4. Flexible Power/Serial Clock Speed Management.
The conversion rate is determined by the serial clock, allowing the power to be reduced as the conversion time is reduced through the serial clock speed increase. These parts also feature a shutdown mode to maximize power efficiency at lower throughput rates.
5. Variable Voltage Reference Input.
6. No Pipeline Delay.
7. Accurate control of the sampling instant via a \overline{CS} input and once-off conversion control.
8. ENOB > 10-bits Typically with 500 mV Reference.

AD7451—SPECIFICATIONS

($V_{DD} = 2.7\text{ V to }5.25\text{ V}$, $f_{SCLK} = 18\text{ MHz}$, $f_S = 1\text{ MSPS}$, $V_{REF} = 2.5\text{ V}$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

Parameter	Test Conditions/Comments	A Version ¹	B Version ¹	Unit
DYNAMIC PERFORMANCE				
Signal-to-Noise Ratio (SNR) ²	$f_{IN} = 100\text{ kHz}$ $V_{DD} = 2.7\text{ V to }5.25\text{ V}$	70	70	dB min
Signal to (Noise + Distortion) (SINAD) ²	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$	69	69	dB min
	$V_{DD} = 4.75\text{ V to }5.25\text{ V}$	70	70	dB min
Total Harmonic Distortion (THD) ²	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$; -78 dB typ	-73	-73	dB max
	$V_{DD} = 4.75\text{ V to }5.25\text{ V}$; -80 dB typ	-75	-75	dB max
Peak Harmonic or Spurious Noise ²	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$; -80 dB typ	-73	-73	dB max
	$V_{DD} = 4.75\text{ V to }5.25\text{ V}$; -82 dB typ	-75	-75	dB max
Intermodulation Distortion (IMD) ²	$f_a = 90\text{ kHz}$; $f_b = 110\text{ kHz}$			
Second Order Terms		-80	-80	dB typ
Third Order Terms		-80	-80	dB typ
Aperture Delay ²		5	5	ns typ
Aperture Jitter ²		50	50	ps typ
Full-Power Bandwidth ^{2, 3}	@ -3 dB	20	20	MHz typ
	@ -0.1 dB	2.5	2.5	MHz typ
DC ACCURACY				
Resolution		12	12	Bits
Integral Nonlinearity (INL) ²		± 1.5	± 1	LSB max
Differential Nonlinearity (DNL) ²	Guaranteed no missed codes to 12 bits	± 0.95	± 0.95	LSB max
Offset Error ²		± 3.5	± 3.5	LSB max
Gain Error ²		± 3	± 3	LSB max
ANALOG INPUT				
Full-Scale Input Span	$V_{IN+} - V_{IN-}$	V_{REF}	V_{REF}	V
Absolute Input Voltage				
V_{IN+}		V_{REF}	V_{REF}	V
V_{IN-} ⁴	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$	$-0.1\text{ to }+0.4$	$-0.1\text{ to }+0.4$	V
	$V_{DD} = 4.75\text{ V to }5.25\text{ V}$	$-0.1\text{ to }+1.5$	$-0.1\text{ to }+1.5$	V
DC Leakage Current		± 1	± 1	$\mu\text{A max}$
Input Capacitance	When in track/hold	30/10	30/10	pF typ
REFERENCE INPUT				
V_{REF} Input Voltage	$\pm 1\%$ tolerance for specified performance	2.5^5	2.5^5	V
DC Leakage Current		± 1	± 1	$\mu\text{A max}$
V_{REF} Input Capacitance	When in track/hold	10/30	10/30	pF typ
LOGIC INPUTS				
Input High Voltage, V_{INH}		2.4	2.4	V min
Input Low Voltage, V_{INL}		0.8	0.8	V max
Input Current, I_{IN}	Typically 10 nA , $V_{IN} = 0\text{ V}$ or V_{DD}	± 1	± 1	$\mu\text{A max}$
Input Capacitance, C_{IN} ⁶		10	10	pF max
LOGIC OUTPUTS				
Output High Voltage, V_{OH}	$V_{DD} = 4.75\text{ V to }5.25\text{ V}$, $I_{SOURCE} = 200\text{ }\mu\text{A}$	2.8	2.8	V min
	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$, $I_{SOURCE} = 200\text{ }\mu\text{A}$	2.4	2.4	V min
Output Low Voltage, V_{OL}	$I_{SINK} = 200\text{ }\mu\text{A}$	0.4	0.4	V max
Floating-State Leakage Current		± 1	± 1	$\mu\text{A max}$
Floating-State Output Capacitance ⁶		10	10	pF max
Output Coding		Straight (natural) binary		
CONVERSION RATE				
Conversion Time	888 ns with an 18 MHz SCLK	16	16	SCLK cycles
Track-and-Hold Acquisition Time ²	Sine wave input	250	250	ns max
	Full-scale step input	290	290	ns max
Throughput Rate		1	1	MSPS max

Parameter	Test Conditions/Comments	A Version ¹	B Version ¹	Unit
POWER REQUIREMENTS				
V_{DD} I_{DD} ^{7, 8}		2.7/5.25	2.7/5.25	V min/max
Normal Mode (Static)	SCLK on or off	0.5	0.5	mA typ
Normal Mode (Operational)	$V_{DD} = 4.75\text{ V to }5.25\text{ V}$	1.95	1.95	mA max
	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$	1.45	1.45	mA max
Full Power-Down Mode	SCLK on or off	1	1	$\mu\text{A max}$
Power Dissipation				
Normal Mode (Operational)	$V_{DD} = 5\text{ V}; 1.55\text{ mW typ for }100\text{ kspss}^7$	9.25	9.25	mW max
	$V_{DD} = 3\text{ V}; 0.6\text{ mW typ for }100\text{ kspss}^7$	4	4	mW max
Full Power-Down	$V_{DD} = 5\text{ V}; \text{SCLK on or off}$	5	5	$\mu\text{W max}$
	$V_{DD} = 3\text{ V}; \text{SCLK on or off}$	3	3	$\mu\text{W max}$

NOTES

¹Temperature ranges as follows: A, B versions: $-40^{\circ}\text{C to }+85^{\circ}\text{C}$.²See Terminology section.³Analog inputs with slew rates exceeding $27\text{ V}/\mu\text{s}$ (full-scale input sine wave $> 3.5\text{ MHz}$) within the acquisition time may cause an incorrect result to be returned by the converter.⁴A small dc input is applied to V_{IN-} to provide a pseudo ground for V_{IN+} .⁵The AD7451 is functional with a reference input in the range $100\text{ mV to }3.5\text{ V}$.⁶Sample tested @ 25°C to ensure compliance.⁷See Power vs. Throughput Rate section.⁸Measured with a midscale dc input.

Specifications subject to change without notice.

AD7441—SPECIFICATIONS¹ ($V_{DD} = 2.7\text{ V to }5.25\text{ V}$, $f_{SCLK} = 18\text{ MHz}$, $f_S = 1\text{ MSPS}$, $V_{REF} = 2.5\text{ V}$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

Parameter	Test Conditions/Comments	B Version ¹	Unit
DYNAMIC PERFORMANCE			
Signal to (Noise + Distortion) (SINAD) ²	$f_{IN} = 100\text{ kHz}$	61	dB min
Total Harmonic Distortion (THD) ²	$2.7\text{ V to }3.6\text{ V}; -77\text{ dB typ}$	-72	dB max
	$4.75\text{ V to }5.25\text{ V}; -79\text{ dB typ}$	-73	dB max
Peak Harmonic or Spurious Noise ²	$2.7\text{ V to }3.6\text{ V}; -80\text{ dB typ}$	-72	dB max
	$4.75\text{ V to }5.25\text{ V}; -82\text{ dB typ}$	-74	dB max
Intermodulation Distortion (IMD) ²	$f_a = 90\text{ kHz}, f_b = 110\text{ kHz}$		
Second Order Terms		-80	dB typ
Third Order Terms		-80	dB typ
Aperture Delay ²		5	ns typ
Aperture Jitter ²		50	ps typ
Full-Power Bandwidth ^{2, 3}	@ -3 dB	20	MHz typ
	@ -0.1 dB	2.5	MHz typ
DC ACCURACY			
Resolution		10	Bits
Integral Nonlinearity (INL) ²		± 0.5	LSB max
Differential Nonlinearity (DNL) ²	Guaranteed no missed codes to 10 bits		
Offset Error ²		± 0.5	LSB max
Gain Error ²		± 1	LSB max
		± 1	LSB max
ANALOG INPUT			
Full-Scale Input Span	$V_{IN+} - V_{IN-}$	V_{REF}	V
Absolute Input Voltage			
V_{IN+}	$V_{DD} 2.7\text{ V to }3.6\text{ V}$	V_{REF}	V
V_{IN-} ⁴	$V_{DD} 4.75\text{ V to }5.25\text{ V}$	-0.1 to +0.4	V
		-0.1 to +1.5	V
DC Leakage Current		± 1	$\mu\text{A max}$
Input Capacitance	When in track/hold	30/10	pF typ

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Parameter	Test Conditions/Comments	B Version ¹	Unit
REFERENCE INPUT V _{REF} Input Voltage	±1% tolerance for specified performance	2.5 ⁵	V
DC Leakage Current V _{REF} Input Capacitance	When in track/hold	±1 10/30	μA max pF typ
LOGIC INPUTS Input High Voltage, V _{INH} Input Low Voltage, V _{INL} Input Current, I _{IN} Input Capacitance, C _{IN} ⁶	Typically 10 nA, V _{IN} = 0 V or V _{DD}	2.4 0.8 ±1 10	V min V max μA max pF max
LOGIC OUTPUTS Output High Voltage, V _{OH} Output Low Voltage, V _{OL} Floating-State Leakage Current Floating-State Output Capacitance ⁶ Output Coding	V _{DD} = 4.75 V to 5.25 V, I _{SOURCE} = 200 μA V _{DD} = 2.7 V to 3.6 V, I _{SOURCE} = 200 μA I _{SINK} = 200 μA	2.8 2.4 0.4 ±1 10 Straight (natural) binary	V min V min V max μA max pF max
CONVERSION RATE Conversion Time Track-and-Hold Acquisition Time ² Throughput Rate	888 ns with an 18 MHz SCLK Sine wave input Step input	16 250 290 1	SCLK cycles ns max ns max MSPS max
POWER REQUIREMENTS V _{DD} I _{DD} ^{7, 8} Normal Mode (Static) Normal Mode (Operational) Full Power-Down Mode Power Dissipation Normal Mode (Operational) Full Power-Down	SCLK on or off V _{DD} = 4.75 V to 5.25 V V _{DD} = 2.7 V to 3.6 V SCLK on or off V _{DD} = 5 V; 1.55 mW typ for 100 ksp/s ⁷ V _{DD} = 3 V; 0.6 mW typ for 100 ksp/s ⁷ V _{DD} = 5 V; SCLK on or off V _{DD} = 3 V; SCLK on or off	2.7/5.25 0.5 1.95 1.25 1 9.25 4 5 3	V min/max mA typ mA max mA max μA max mW max mW max μW max μW max

NOTES

¹Temperature ranges as follows: B versions: -40°C to +85°C.

²See Terminology section.

³Analog inputs with slew rates exceeding 27 V/μs (full-scale input sine wave > 3.5 MHz) within the acquisition time may cause an incorrect result to be returned by the converter.

⁴A small dc input is applied to V_{IN-} to provide a pseudo ground for V_{IN+}.

⁵The AD7441 is functional with a reference input in the range 100 mV to 3.5 V.

⁶Sample tested @ 25°C to ensure compliance.

⁷See Power vs. Throughput Rate section.

⁸Measured with a midscale dc input.

Specifications subject to change without notice.

TIMING SPECIFICATIONS^{1,2} ($V_{DD} = 2.7\text{ V to }5.25\text{ V}$, $f_{SCLK} = 18\text{ MHz}$, $f_S = 1\text{ MSPS}$, $V_{REF} = 2.5\text{ V}$, $T_A = T_{MIN}\text{ to }T_{MAX}$, unless otherwise noted.)

Parameter	Limit at T_{MIN} , T_{MAX}	Unit	Description
f_{SCLK} ³	10 18	kHz min MHz max	$t_{SCLK} = 1/f_{SCLK}$
$t_{CONVERT}$	$16 \times t_{SCLK}$ 888	ns max	
t_{QUIET}	60	ns min	Minimum Quiet Time between the End of a Serial Read and the Next Falling Edge of \overline{CS}
t_1	10	ns min	Minimum \overline{CS} Pulsewidth
t_2	10	ns min	\overline{CS} Falling Edge to SCLK Falling Edge Setup Time
t_3 ⁴	20	ns max	Delay from \overline{CS} Falling Edge Until SDATA Three-State Disabled
t_4 ⁴	40	ns max	Data Access Time After SCLK Falling Edge
t_5	$0.4 t_{SCLK}$	ns min	SCLK High Pulsewidth
t_6	$0.4 t_{SCLK}$	ns min	SCLK Low Pulsewidth
t_7	10	ns min	SCLK Edge to Data Valid Hold Time
t_8 ⁵	10 35	ns min ns max	SCLK Falling Edge to SDATA Three-State Enabled
$t_{POWER-UP}$ ⁶	1	$\mu\text{s max}$	Power-Up Time from Full Power-Down

NOTES

¹Sample tested at 25°C to ensure compliance. All input signals are specified with $t_r = t_f = 5\text{ ns}$ (10% to 90% of V_{DD}) and timed from a voltage level of 1.6 V.

²See Figure 1, Figure 2, and the Serial Interface section.

³Mark/Space ratio for the SCLK input is 40/60 to 60/40.

⁴Measured with the load circuit of Figure 3 and defined as the time required for the output to cross 0.8 V or 2.4 V with $V_{DD} = 5\text{ V}$ and time for an output to cross 0.4 V or 2.0 V for $V_{DD} = 3\text{ V}$.

⁵ t_8 is derived from the measured time taken by the data outputs to change 0.5 V when loaded with the circuit of Figure 3. The measured number is then extrapolated back to remove the effects of charging or discharging the 25 pF capacitor. This means that the time, t_8 , quoted in the timing characteristics is the true bus relinquish time of the part and is independent of the bus loading.

⁶See Power-Up Time section.

Specifications subject to change without notice.

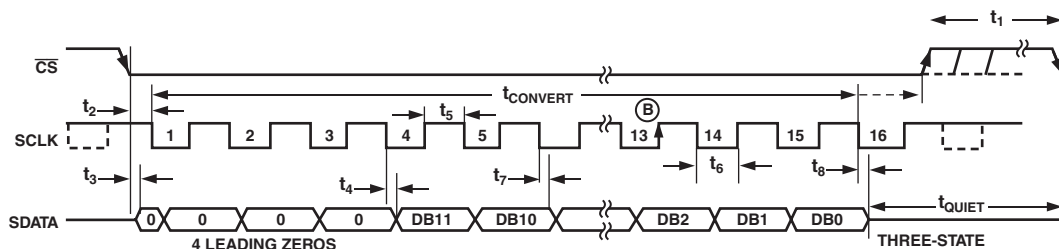


Figure 1. AD7451 Serial Interface Timing Diagram

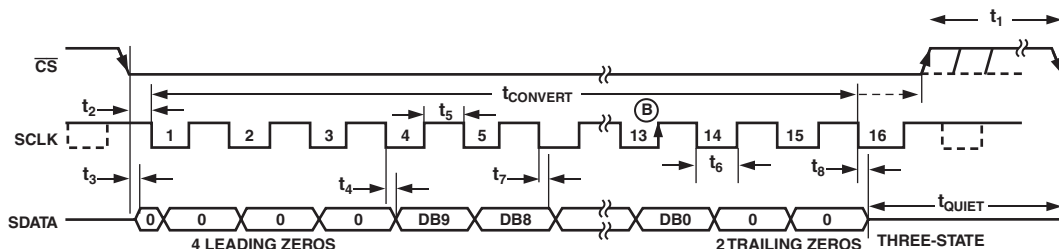


Figure 2. AD7441 Serial Interface Timing Diagram

AD7441/AD7451

ABSOLUTE MAXIMUM RATINGS¹

(T_A = 25°C, unless otherwise noted.)

V _{DD} to GND	−0.3 V to +7 V
V _{IN+} to GND	−0.3 V to V _{DD} + 0.3 V
V _{IN−} to GND	−0.3 V to V _{DD} + 0.3 V
Digital Input Voltage to GND	−0.3 V to +7 V
Digital Output Voltage to GND	−0.3 V to V _{DD} + 0.3 V
V _{REF} to GND	−0.3 V to V _{DD} + 0.3 V
Input Current to Any Pin Except Supplies ²	±10 mA
Operating Temperature Range	
Commercial (A, B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
θ _{JA} Thermal Impedance	205.9°C/W (MSOP)
	211.5°C/W (SOT-23)
θ _{JC} Thermal Impedance	43.74°C/W (MSOP)
	91.99°C/W (SOT-23)
Lead Temperature, Soldering	
Vapor Phase (60 secs)	215°C
Infrared (15 secs)	220°C
ESD	1 kV

NOTES

¹Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²Transient currents of up to 100 mA will not cause SCR latch-up.

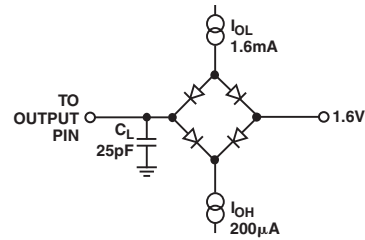


Figure 3. Load Circuit for Digital Output Timing Specifications

ORDERING GUIDE

Model	Temperature Range	Linearity Error (LSB) ¹	Package Description	Package Option	Branding
AD7451ART-R2	−40°C to +85°C	±1.5	8-Lead SOT-23	RT-8	C06
AD7451ART-REEL7	−40°C to +85°C	±1.5	8-Lead SOT-23	RT-8	C06
AD7451ARM	−40°C to +85°C	±1.5	8-Lead MSOP	RM-8	C06
AD7451ARM-REEL7	−40°C to +85°C	±1.5	8-Lead MSOP	RM-8	C06
AD7451BRT-R2	−40°C to +85°C	±1	8-Lead SOT-23	RT-8	C05
AD7451BRT-REEL7	−40°C to +85°C	±1	8-Lead SOT-23	RT-8	C05
AD7451BRM	−40°C to +85°C	±1	8-Lead MSOP	RM-8	C05
AD7451BRM-REEL7	−40°C to +85°C	±1	8-Lead MSOP	RM-8	C05
AD7441BRT-R2	−40°C to +85°C	±0.5	8-Lead SOT-23	RT-8	C0F
AD7441BRT-REEL7	−40°C to +85°C	±0.5	8-Lead SOT-23	RT-8	C0F
AD7441BRM	−40°C to +85°C	±0.5	8-Lead MSOP	RM-8	C0F
AD7441BRM-REEL7	−40°C to +85°C	±0.5	8-Lead MSOP	RM-8	C0F
EVAL-AD7451CB ²			Evaluation Board		
EVAL-AD7441CB ²			Evaluation Board		
EVAL-CONTROL BRD ^{2,3}			Controller Board		

NOTES

¹Linearity error here refers to integral nonlinearity error.

²This can be used as a standalone evaluation board or in conjunction with the evaluation board controller for evaluation/demonstration purposes.

³The evaluation board controller is a complete unit allowing a PC to control and communicate with all Analog Devices evaluation boards ending in the CB designators. To order a complete Evaluation Kit, you will need to order the ADC evaluation board, i.e., EVAL-AD7451CB or EVAL-AD7441CB, the EVAL-CONTROL BRD2, and a 12 V ac transformer. See the AD7451/AD7441 application note for more information.

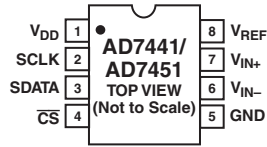
CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD7441/AD7451 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

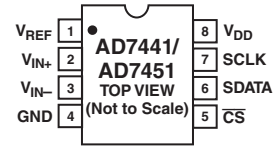


PIN CONFIGURATIONS

8-Lead SOT-23



8-Lead MSOP



PIN FUNCTION DESCRIPTIONS

Mnemonic	Function
V_{REF}	Reference Input for the AD7441/AD7451. An external reference in the range 100 mV to 3.5 V must be applied to this input. The specified reference input is 2.5 V. This pin should be decoupled to GND with a capacitor of at least 0.1 μ F.
V_{IN+}	Noninverting Analog Input.
V_{IN-}	Inverting Input. This pin sets the ground reference point for the V_{IN+} input. Connect to ground or to a dc offset to provide a pseudo ground.
GND	Analog Ground. Ground reference point for all circuitry on the AD7441/AD7451. All analog input signals and any external reference signal should be referred to this GND voltage.
\overline{CS}	Chip Select. Active low logic input. This input provides the dual function of initiating a conversion on the AD7441/AD7451 and framing the serial data transfer.
SDATA	Serial Data. Logic output. The conversion result from the AD7441/AD7451 is provided on this output as a serial data stream. The bits are clocked out on the falling edge of the SCLK input. The data stream of the AD7451 consists of four leading zeros followed by the 12 bits of conversion data that are provided MSB first; the data stream of the AD7441 consists of four leading zeros, followed by the 10 bits of conversion data, followed by two trailing zeros. In both cases, the output coding is straight (natural) binary.
SCLK	Serial Clock. Logic input. SCLK provides the serial clock for accessing data from the part. This clock input is also used as the clock source for the conversion process.
V_{DD}	Power Supply Input. V_{DD} is 2.7 V to 5.25 V. This supply should be decoupled to GND with a 0.1 μ F capacitor and a 10 μ F tantalum capacitor.

AD7441/AD7451

TERMINOLOGY

Signal to (Noise + Distortion) Ratio

This is the measured ratio of signal to (noise + distortion) at the output of the ADC. The signal is the rms amplitude of the fundamental. Noise is the sum of all nonfundamental signals up to half the sampling frequency ($f_s/2$), excluding dc. The ratio is dependent on the number of quantization levels in the digitization process; the more levels, the smaller the quantization noise. The theoretical signal to (noise + distortion) ratio for an ideal N-bit converter with a sine wave input is given by

$$\text{Signal to (Noise + Distortion)} = (6.02N + 1.76) \text{ dB}$$

Thus for a 12-bit converter, this is 74 dB and for a 10-bit converter this is 62 dB.

Total Harmonic Distortion (THD)

Total harmonic distortion is the ratio of the rms sum of harmonics to the fundamental. For the AD7441/AD7451, it is defined as

$$\text{THD}(\text{dB}) = 20 \log \frac{\sqrt{V_2^2 + V_3^2 + V_4^2 + V_5^2 + V_6^2}}{V_1}$$

where V_1 is the rms amplitude of the fundamental and V_2 , V_3 , V_4 , V_5 , and V_6 are the rms amplitudes of the second to the sixth harmonics.

Peak Harmonic or Spurious Noise

Peak harmonic or spurious noise is defined as the ratio of the rms value of the next largest component in the ADC output spectrum (up to $f_s/2$ and excluding dc) to the rms value of the fundamental. Normally, the value of this specification is determined by the largest harmonic in the spectrum, but for ADCs where the harmonics are buried in the noise floor, it will be a noise peak.

Intermodulation Distortion

With inputs consisting of sine waves at two frequencies, f_a and f_b , any active device with nonlinearities will create distortion products at sum and difference frequencies of $m f_a \pm n f_b$ where $m, n = 0, 1, 2, 3$, and so on. Intermodulation distortion terms are those for which neither m nor n are equal to zero. For example, the second order terms include $(f_a + f_b)$ and $(f_a - f_b)$, while the third order terms include $(2f_a + f_b)$, $(2f_a - f_b)$, $(f_a + 2f_b)$ and $(f_a - 2f_b)$.

The AD7441/AD7451 is tested using the CCIF standard where two input frequencies near the top end of the input bandwidth are used. In this case, the second order terms are usually distanced in frequency from the original sine waves while the

third order terms are usually at a frequency close to the input frequencies. As a result, the second and third order terms are specified separately. The calculation of the intermodulation distortion is as per the THD specification where it is the ratio of the rms sum of the individual distortion products to the rms amplitude of the sum of the fundamentals expressed in dB.

Aperture Delay

This is the amount of time from the leading edge of the sampling clock until the ADC actually takes the sample.

Aperture Jitter

This is the sample to sample variation in the effective point in time at which the actual sample is taken.

Full Power Bandwidth

The full power bandwidth of an ADC is that input frequency at which the amplitude of the reconstructed fundamental is reduced by 0.1 dB or 3 dB for a full scale input.

Integral Nonlinearity (INL)

This is the maximum deviation from a straight line passing through the endpoints of the ADC transfer function.

Differential Nonlinearity (DNL)

This is the difference between the measured and the ideal 1 LSB change between any two adjacent codes in the ADC.

Offset Error

This is the deviation of the first code transition (000...000 to 000...001) from the ideal (i.e., AGND + 1 LSB)

Gain Error

This is the deviation of the last code transition (111...110 to 111...111) from the ideal (i.e., $V_{REF} - 1$ LSB), after the Offset Error has been adjusted out.

Track-and-Hold Acquisition Time

The track-and-hold acquisition time is the minimum time required for the track and hold amplifier to remain in track mode for its output to reach and settle to within 0.5 LSB of the applied input signal.

Power Supply Rejection Ratio (PSRR)

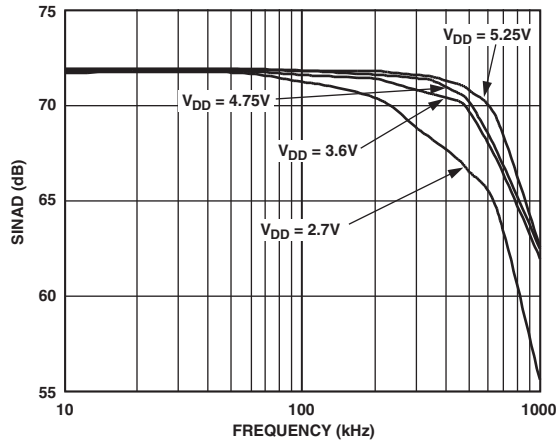
The power supply rejection ratio is defined as the ratio of the power in the ADC output at full-scale frequency, f , to the power of a 100 mV p-p sine wave applied to the ADC V_{DD} supply of frequency f_s . The frequency of this input varies from 1 kHz to 1 MHz.

$$\text{PSRR}(\text{dB}) = 10 \log(P_f/P_{f_s})$$

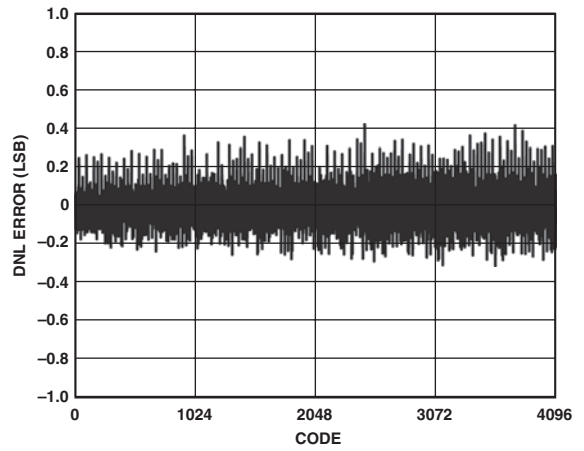
P_f is the power at frequency f in the ADC output; P_{f_s} is the power at frequency f_s in the ADC output.

Typical Performance Characteristics—AD7441/AD7451

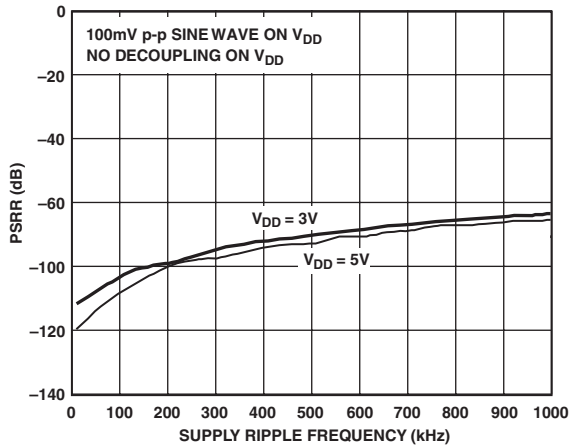
(Default Conditions: $T_A = 25^\circ\text{C}$, $f_S = 1 \text{ MSPS}$, $f_{\text{SCLK}} = 18 \text{ MHz}$, $V_{\text{DD}} = 2.7 \text{ V to } 5.25 \text{ V}$, $V_{\text{REF}} = 2.5 \text{ V}$, unless otherwise noted.)



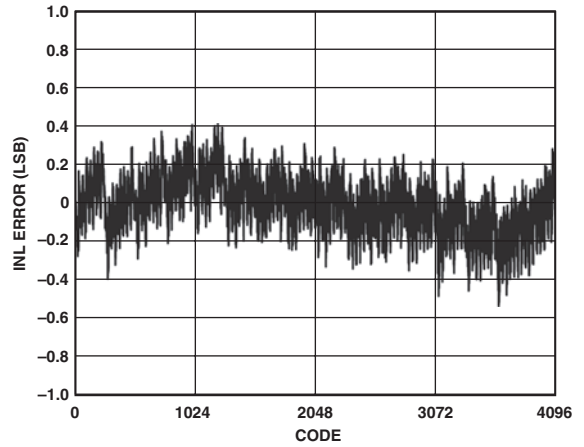
TPC 1. SINAD vs. Analog Input Frequency for the AD7451 for Various Supply Voltages



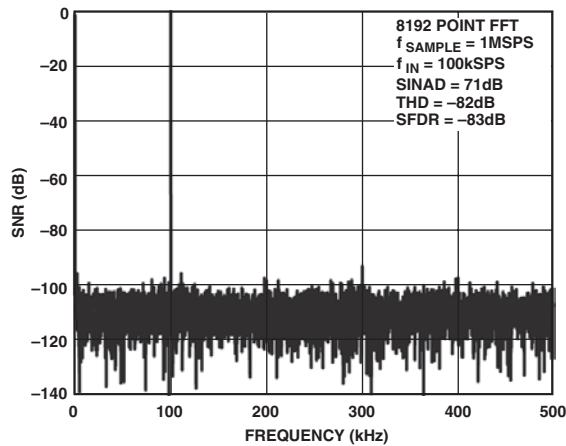
TPC 4. Typical DNL For the AD7451 for $V_{\text{DD}} = 5 \text{ V}$



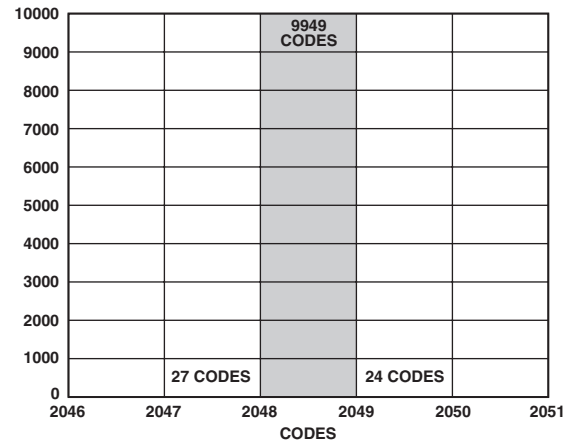
TPC 2. PSRR vs. Supply Ripple Frequency without Supply Decoupling



TPC 5. Typical INL For the AD7451 for $V_{\text{DD}} = 5 \text{ V}$

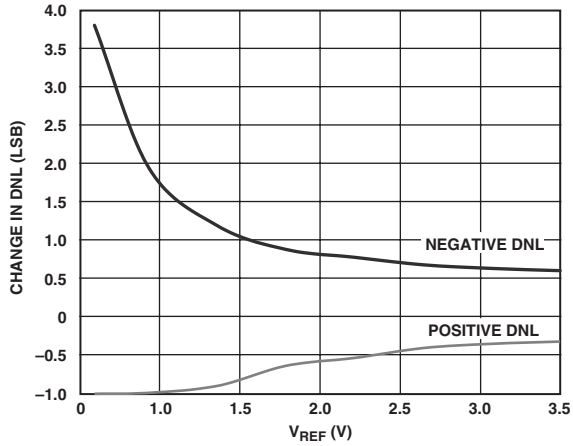


TPC 3. AD7451 Dynamic Performance for $V_{\text{DD}} = 5 \text{ V}$

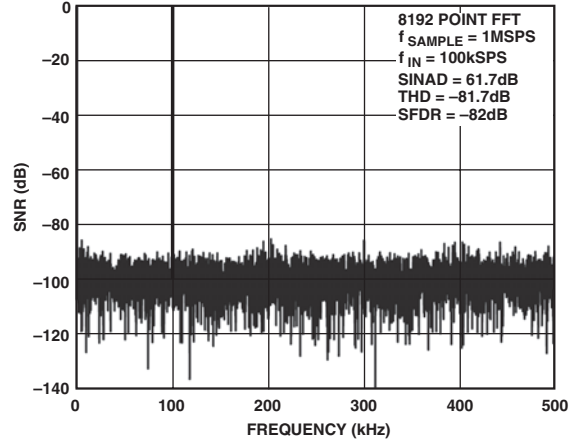


TPC 6. Histogram of 10,000 Conversions of a DC Input for the AD7451

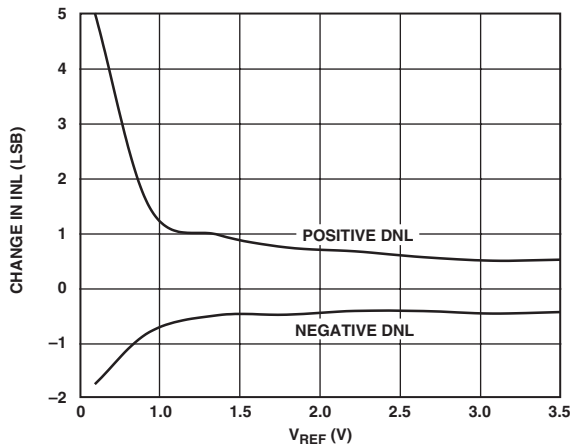
AD7441/AD7451



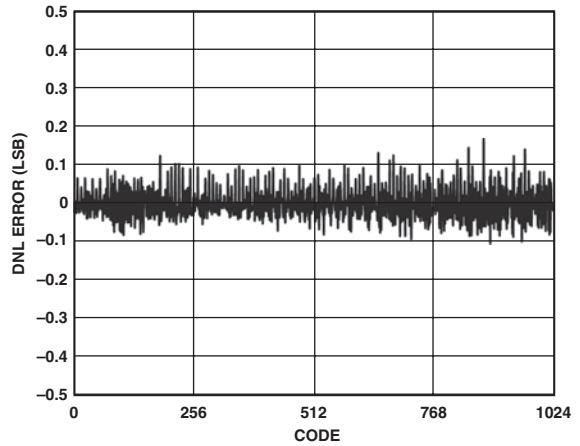
TPC 7. Change in DNL vs. V_{REF} for $V_{DD} = 5\text{ V}$



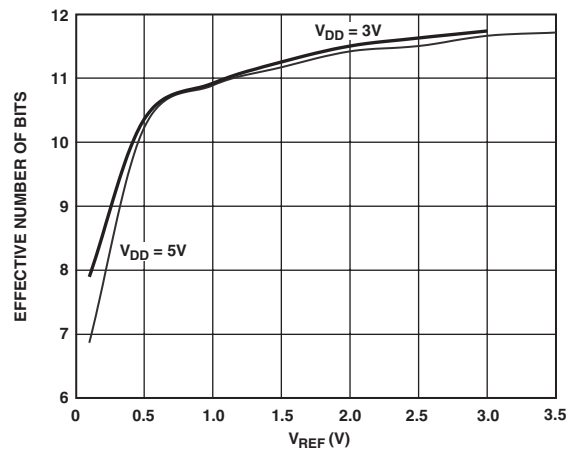
TPC 10. AD7441 Dynamic Performance



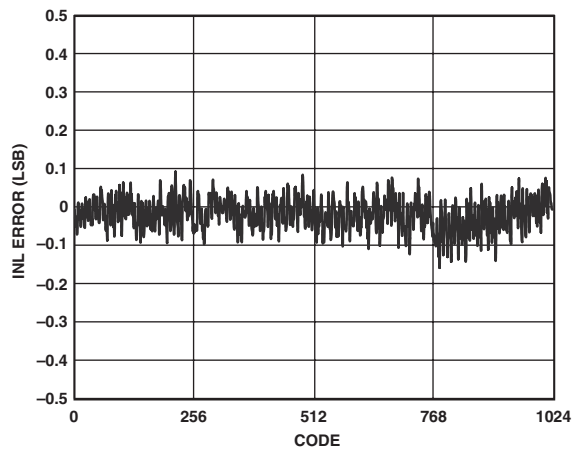
TPC 8. Change in INL vs. V_{REF} for $V_{DD} = 5\text{ V}$



TPC 11. Typical DNL for the AD7441



TPC 9. ENOB vs. V_{REF} for $V_{DD} = 5\text{ V}$



TPC 12. Typical INL for the AD7441

CIRCUIT INFORMATION

The AD7441/AD7451 are 10-bit and 12-bit, fast, low power, single supply, successive approximation analog-to-digital converters (ADC) with a pseudo differential analog input. They operate with a single 2.7 V to 5.25 V power supply and are capable of throughput rates up to 1 MSPS when supplied with an 18 MHz SCLK. They require an external reference to be applied to the V_{REF} pin.

The AD7441/AD7451 have an on-chip differential track-and-hold amplifier, a successive approximation (SAR) ADC, and a serial interface, housed in either an 8-lead SOT-23 or MSOP package. The serial clock input accesses data from the part and provides the clock source for the successive approximation ADC. The AD7441/AD7451 feature a power-down option for reduced power consumption between conversions. The power-down feature is implemented across the standard serial interface, as described in the Modes of Operation section.

CONVERTER OPERATION

The AD7441/AD7451 is a successive approximation ADC based around two capacitive DACs. Figures 4 and 5 show simplified schematics of the ADC in the acquisition and conversion phase, respectively. The ADC is comprised of control logic, a SAR, and two capacitive DACs. In Figure 4 (acquisition phase), SW3 is closed and SW1 and SW2 are in Position A, the comparator is held in a balanced condition, and the sampling capacitor arrays acquire the differential signal on the input.

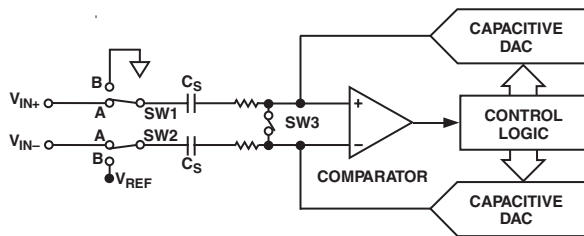


Figure 4. ADC Acquisition Phase

When the ADC starts a conversion (Figure 5), SW3 will open and SW1 and SW2 will move to Position B, causing the comparator to become unbalanced. Both inputs are disconnected once the conversion begins. The control logic and the charge redistribution DACs are used to add and subtract fixed amounts of charge from the sampling capacitor arrays to bring the comparator back into a balanced condition. When the comparator is rebalanced, the conversion is complete. The control logic generates the ADC's output code. The output impedances of the sources driving the V_{IN+} and the V_{IN-} pins must be matched; otherwise the two inputs will have different settling times, resulting in errors.

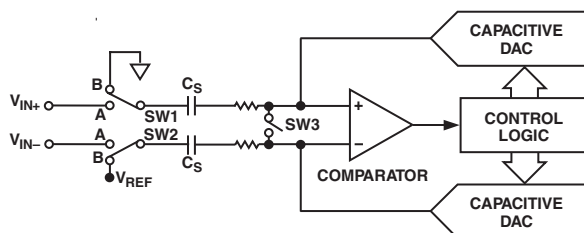


Figure 5. ADC Conversion Phase

ADC TRANSFER FUNCTION

The output coding for the AD7441/AD7451 is straight (natural) binary. The designed code transitions occur at successive LSB values (i.e., 1 LSB, 2 LSB, and so on). The LSB size of the AD7451 is $V_{REF}/4096$ and the LSB size of the AD7441 is $V_{REF}/1024$. The ideal transfer characteristic of the AD7441/AD7451 is shown in Figure 6.

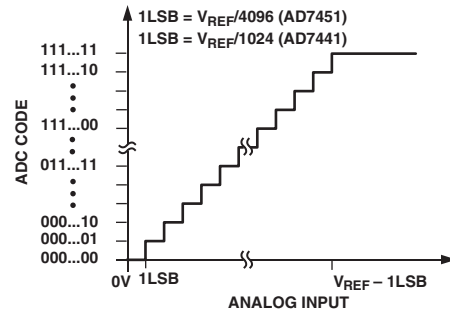


Figure 6. AD7441/AD7451 Ideal Transfer Characteristic

TYPICAL CONNECTION DIAGRAM

Figure 7 shows a typical connection diagram for the AD7441/AD7451. In this setup the GND pin is connected to the analog ground plane of the system. The V_{REF} pin is connected to the AD780, a 2.5 V decoupled reference source. The signal source, is connected to the V_{IN+} analog input via a unity gain buffer. A dc voltage is connected to the V_{IN-} pin to provide a pseudo ground for the V_{IN+} input. The V_{DD} pin should be decoupled to AGND with a 1 μ F tantalum capacitor in parallel with a 0.1 μ F ceramic capacitor. The reference pin should be decoupled to AGND with a capacitor of at least 0.1 μ F. The conversion result is output in a 16-bit word with four leading zeros followed by the MSB of the 12-bit or 10-bit result. The 10-bit result of the AD7441 is followed by two trailing zeros.

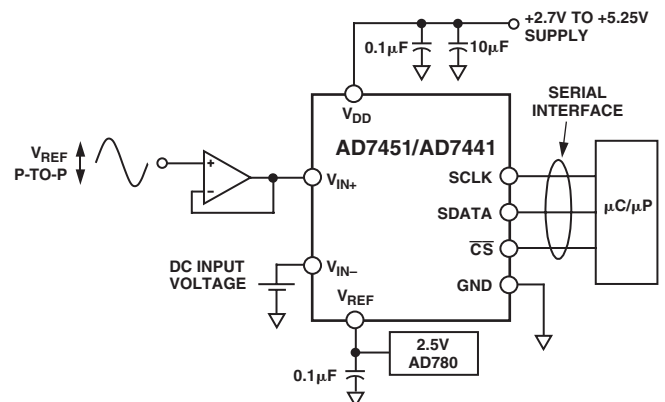


Figure 7. Typical Connection Diagram

AD7441/AD7451

ANALOG INPUT

The AD7441/AD7451 has a pseudo differential analog input. The V_{IN+} input is coupled to the signal source and must have an amplitude of V_{REF} p-p to make use of the full dynamic range of the part. A dc input is applied to the V_{IN-} . The voltage applied to this input provides an offset from ground or a pseudo ground for the V_{IN+} input. The main benefit of pseudo differential inputs is that they separate the analog input signal ground from the ADC's ground, allowing dc common-mode voltages to be cancelled.

Because the ADC operates from a single supply, it is necessary to level shift ground based bipolar signals to comply with the input requirements. An op amp (for example, the AD8021) can be configured to rescale and level shift a ground based (bipolar) signal so that it is compatible with the input range of the AD7441/AD7451. See Figure 8.

When a conversion takes place, the pseudo ground corresponds to 0 and the maximum analog input corresponds to 4096 for the AD7451 and 1024 for the AD7441.

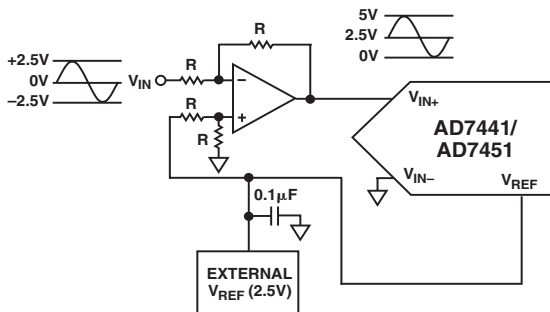


Figure 8. Op Amp Configuration to Level Shift a Bipolar Input Signal

Analog Input Structure

Figure 9 shows the equivalent circuit of the analog input structure of the AD7441/AD7451. The four diodes provide ESD protection for the analog inputs. Care must be taken to ensure that the analog input signals never exceed the supply rails by more than 300 mV. This will cause these diodes to become forward biased and start conducting into the substrate. These diodes can conduct up to 10 mA without causing irreversible damage to the part. The capacitors, C1 in Figure 9, are typically 4 pF and can be attributed primarily to pin capacitance. The resistors are lumped components made up of the on resistance of the switches. The value of these resistors is typically about 100 Ω . The capacitors, C2, are the ADC's sampling capacitors and have a capacitance of 16 pF typically.

For ac applications, removing high frequency components from the analog input signal through the use of an RC low-pass filter on the relevant analog input pins is recommended. In applications where harmonic distortion and the signal-to-noise ratio are critical, the analog input should be driven from a low impedance source. Large source impedances will significantly affect the ac performance of the ADC, which may necessitate the use of an input buffer amplifier. The choice of the op amp will be a function of the particular application.

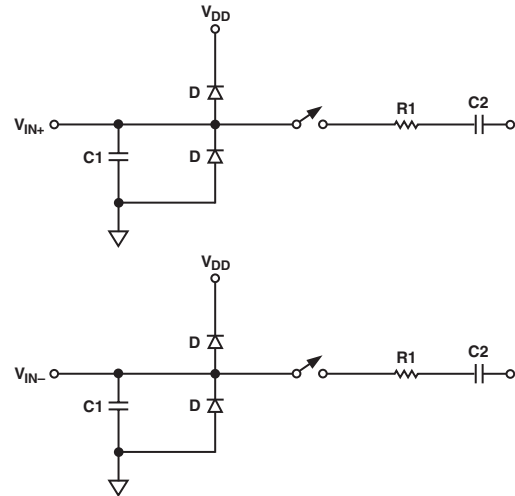


Figure 9. Equivalent Analog Input Circuit. Conversion Phase—Switches Open; Track Phase—Switches Closed

When no amplifier is used to drive the analog input, the source impedance should be limited to low values. The maximum source impedance depends on the amount of total harmonic distortion (THD) that can be tolerated. The THD increases as the source impedance increases and performance degrades. Figure 10 shows a graph of the THD versus analog input signal frequency for different source impedances.

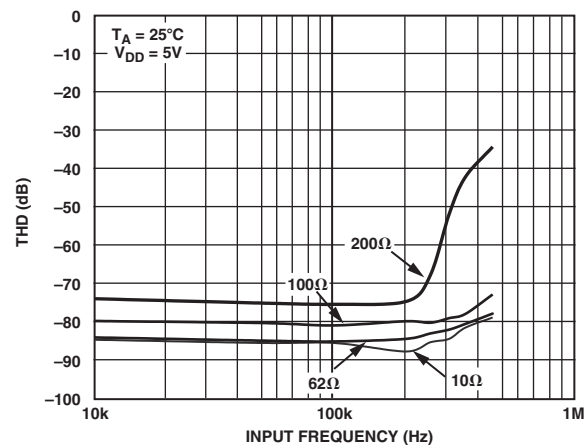


Figure 10. THD vs. Analog Input Frequency for Various Source Impedances

Figure 11 shows a graph of THD versus analog input frequency for various supply voltages, while sampling at 1 MSPS with an SCLK of 18 MHz. In this case the source impedance is 10 Ω.

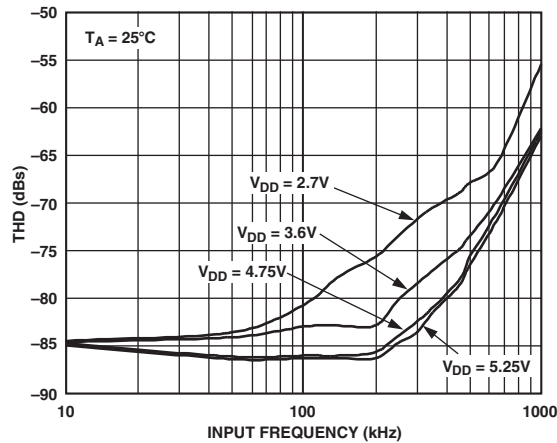


Figure 11. THD vs. Analog Input Frequency for Various Supply Voltages

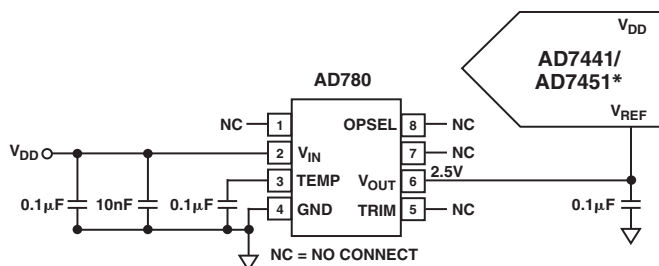
DIGITAL INPUTS

The digital inputs applied to the AD7441/AD7451 are not limited by the maximum ratings that limit the analog inputs. Instead the digital inputs applied, i.e., \overline{CS} and SCLK, can go to 7 V and are not restricted by the $V_{DD} + 0.3$ V limits as on the analog input.

The main advantage of the inputs not being restricted to the $V_{DD} + 0.3$ V limit is that power supply sequencing issues are avoided. If \overline{CS} or SCLK are applied before V_{DD} , there is no risk of latch-up as there would be on the analog inputs if a signal greater than 0.3 V were applied prior to V_{DD} .

REFERENCE SECTION

An external source is required to supply the reference to the AD7441/AD7451. This reference input can range from 100 mV to 3.5 V. The specified reference is 2.5 V for the power supply range 2.7 V to 5.25 V. The reference input chosen for an application should never be greater than the power supply. Errors in the reference source result in gain errors in the AD7441/AD7451 transfer function and add to the specified full-scale errors of the part. A capacitor of at least 0.1 μF should be placed on the V_{REF} pin. Suitable reference sources for the AD7441/AD7451 include the AD780 and the ADR421. Figure 12 shows a typical connection diagram for the V_{REF} pin.



*ADDITIONAL PINS OMITTED FOR CLARITY

Figure 12. Typical V_{REF} Connection Diagram for $V_{DD} = 5$ V

SERIAL INTERFACE

Figures 1 and 2 show detailed timing diagrams for the serial interface of the AD7451 and the AD7441, respectively. The serial clock provides the conversion clock and also controls the transfer of data from the device during conversion. \overline{CS} initiates the conversion process and frames the data transfer. The falling edge of \overline{CS} puts the track-and-hold into hold mode and takes the bus out of three-state. The analog input is sampled and the conversion initiated at this point. The conversion will require 16 SCLK cycles to complete.

Once 13 SCLK falling edges have occurred, the track-and-hold will go back into track mode on the next SCLK rising edge, as shown at Point B in Figures 1 and 2. On the 16th SCLK falling edge, the SDATA line will go back into three-state.

If the rising edge of \overline{CS} occurs before 16 SCLKs have elapsed, the conversion will be terminated and the SDATA line will go back into three-state.

The conversion result from the AD7441/AD7451 is provided on the SDATA output as a serial data stream. The bits are clocked out on the falling edge of the SCLK input. The data stream of the AD7451 consists of four leading zeros, followed by 12 bits of conversion data, provided MSB first. The data stream of the AD7441 consists of four leading zeros, followed by the 10 bits of conversion data, followed by two trailing zeros, which is also provided MSB first. In both cases, the output coding is straight (natural) binary.

Sixteen serial clock cycles are required to perform a conversion and to access data from the AD7441/AD7451. \overline{CS} going low provides the first leading zero to be read in by the microcontroller or DSP. The remaining data is then clocked out on the subsequent SCLK falling edges, beginning with the second leading zero. Thus the first falling clock edge on the serial clock provides the second leading zero. The final bit in the data transfer is valid on the 16th falling edge, having been clocked out on the previous (15th) falling edge. Once the conversion is complete and the data has been accessed after the 16 clock cycles, it is important to ensure that, before the next conversion is initiated, enough time is left to meet the acquisition and quiet time specifications—see the timing examples that follow. To achieve 1 MSPS with an 18 MHz clock, an 18-clock burst will perform the conversion and leave enough time before the next conversion for the acquisition and quiet time.

In applications with a slower SCLK, it may be possible to read in data on each SCLK rising edge, i.e., the first rising edge of SCLK after the \overline{CS} falling edge would have the leading zero provided and the 15th SCLK edge would have DB0 provided.

Timing Example 1

Having $F_{SCLK} = 18$ MHz and a throughput rate of 1 MSPS gives a cycle time of

$$1 / \text{Throughput} = 1 / 1000000 = 1 \mu\text{s}$$

A cycle consists of

$$t_2 + 12.5(1 / F_{SCLK}) + t_{ACQ} = 1 \mu\text{s}$$

Therefore if $t_2 = 10$ ns, then

$$10 \text{ ns} + 12.5(1 / 18 \text{ MHz}) + t_{ACQ} = 1 \mu\text{s}$$

$$t_{ACQ} = 296 \text{ ns}$$

This 296 ns satisfies the requirement of 290 ns for t_{ACQ} .

AD7441/AD7451

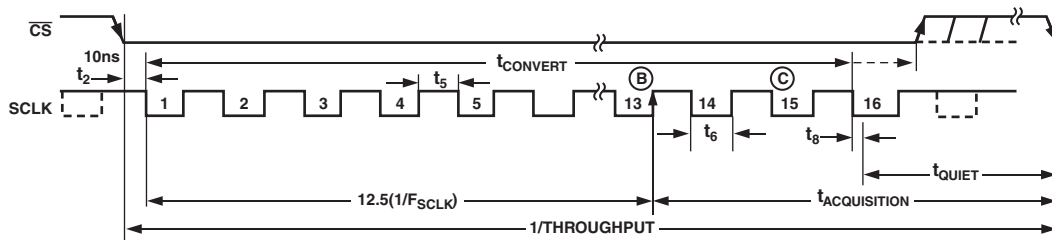


Figure 13. Serial Interface Timing Example

From Figure 13, t_{ACQ} comprises

$$2.5(1/F_{SCLK}) + t_8 + t_{QUIET}$$

where $t_8 = 35$ ns. This allows a value of 122 ns for t_{QUIET} , satisfying the minimum requirement of 60 ns.

Timing Example 2

Having $F_{SCLK} = 5$ MHz and a throughput rate of 315 kSPS gives a cycle time of

$$1/Throughput = 1/315000 = 3.174 \mu s$$

A cycle consists of

$$t_2 + 12.5(1/F_{SCLK}) + t_{ACQ} = 3.174 \mu s$$

Therefore if t_2 is 10 ns, then

$$10 \text{ ns} + 12.5(1/5 \text{ MHz}) + t_{ACQ} = 3.174 \mu s$$

$$t_{ACQ} = 664 \text{ ns}$$

This 664 ns satisfies the requirement of 290 ns for t_{ACQ} .

From Figure 13, t_{ACQ} comprises

$$2.5(1/F_{SCLK}) + t_8 + t_{QUIET}$$

where $t_8 = 35$ ns. This allows a value of 129 ns for t_{QUIET} , satisfying the minimum requirement of 60 ns.

As in this example and with other slower clock values, the signal may already be acquired before the conversion is complete, but it is still necessary to leave 60 ns minimum t_{QUIET} between conversions. In Example 2, the signal should be fully acquired at approximately Point C in Figure 13.

MODES OF OPERATION

The mode of operation of the AD7451 and the AD7441 is selected by controlling the logic state of the \overline{CS} signal during a conversion. There are two possible modes of operation, normal mode and power-down mode. The point at which \overline{CS} is pulled high after the conversion has been initiated determines whether the AD7441/AD7451 will enter the power-down mode. Similarly, if already in power-down, \overline{CS} controls whether the devices will return to normal operation or remain in power-down. These modes of operation are designed to provide flexible power management options. These options can be chosen to optimize the power dissipation/throughput rate ratio for differing application requirements.

Normal Mode

This mode is intended for fastest throughput rate performance. The user does not have to worry about any power-up times with the AD7441/AD7451 remaining fully powered up all the time. Figure 14 shows the general diagram of the operation of the AD7441/AD7451 in this mode. The conversion is initiated on the falling edge of \overline{CS} , as described in the Serial Interface section. To ensure that the part remains fully powered up, \overline{CS} must remain low until at least 10 SCLK falling edges have elapsed after the falling edge of \overline{CS} .

If \overline{CS} is brought high any time after the 10th SCLK falling edge, but before the 16th SCLK falling edge, the part will remain powered up but the conversion will be terminated and SDATA will go back into three-state. Sixteen serial clock cycles are required to complete the conversion and access the complete conversion result. \overline{CS} may idle high until the next conversion or may idle low until sometime prior to the next conversion. Once a data transfer is complete, i.e., when SDATA has returned to three-state, another conversion can be initiated after the quiet time, t_{QUIET} , has elapsed by again bringing \overline{CS} low.

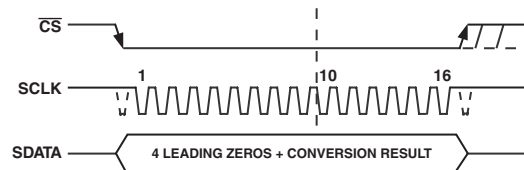


Figure 14. Normal Mode Operation

Power-Down Mode

This mode is intended for use in applications where slower throughput rates are required; either the ADC is powered down between each conversion, or a series of conversions may be performed at a high throughput rate and the ADC is then powered down for a relatively long duration between these bursts of several conversions. When the AD7441/AD7451 is in power-down mode, all analog circuitry is powered down. For the AD7441/AD7451 to enter power-down mode, the conversion process must be interrupted by bringing \overline{CS} high anywhere after the second falling edge of SCLK and before the tenth falling edge of SCLK, as shown in Figure 15.

Once \overline{CS} has been brought high in this window of SCLKs, the part will enter power-down and the conversion that was initiated by the falling edge of \overline{CS} will be terminated and SDATA will go back into three-state. The time from the rising edge of \overline{CS} to SDATA three-state enabled will never be greater than t_3 (see the Timing Specifications). If \overline{CS} is brought high before the second SCLK falling edge, the part will remain in normal mode and will not power down. This will avoid accidental power-down due to glitches on the \overline{CS} line.

To exit this mode of operation and power up the AD7441/AD7451 again, a dummy conversion is performed. On the falling edge of \overline{CS} the device will begin to power up, and will continue to power up as long as \overline{CS} is held low until after the falling edge of the 10th SCLK. The device will be fully powered up after 1 μ sec has elapsed and, as shown in Figure 16, valid data will result from the next conversion.

If \overline{CS} is brought high before the 10th falling edge of SCLK, the AD7441/AD7451 will again go back into power-down. This avoids accidental power-up due to glitches on the \overline{CS} line or an inadvertent burst of eight SCLK cycles while \overline{CS} is low. So although the device may begin to power up on the falling edge of \overline{CS} , it will again power down on the rising edge of \overline{CS} as long as it occurs before the 10th SCLK falling edge.

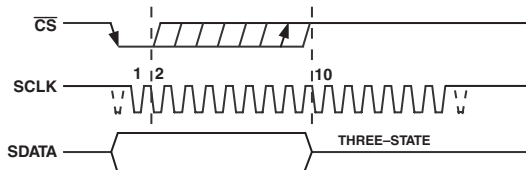


Figure 15. Entering Power-Down Mode

Power-Up Time

The power-up time of the AD7441/AD7451 is typically 1 μ s, which means that with any frequency of SCLK up to 18 MHz, one dummy cycle will always be sufficient to allow the device to power up. Once the dummy cycle is complete, the ADC will be fully powered up and the input signal will be acquired properly. The quiet time, t_{QUIET} , must still be allowed—from the point at which the bus goes back into three-state after the dummy conversion to the next falling edge of \overline{CS} .

When running at the maximum throughput rate of 1 MSPS, the AD7441/AD7451 will power up and acquire a signal within ± 0.5 LSB in one dummy cycle, i.e., 1 μ s. When powering up from the power-down mode with a dummy cycle, as in Figure 16,

the track-and-hold, which was in hold mode while the part was powered down, returns to track mode after the first SCLK edge the part receives after the falling edge of \overline{CS} . This is shown as Point A in Figure 16.

Although at any SCLK frequency one dummy cycle is sufficient to power up the device and acquire V_{IN} , it does not necessarily mean that a full dummy cycle of 16 SCLKs must always elapse to power up the device and acquire V_{IN} fully; 1 μ s will be sufficient to power up the device and acquire the input signal.

For example, if a 5 MHz SCLK frequency was applied to the ADC, the cycle time would be 3.2 μ s (i.e., $1/(5 \text{ MHz}) \times 16$). In one dummy cycle, 3.2 μ s, the part would be powered up and V_{IN} acquired fully. However after 1 μ s with a 5 MHz SCLK, only five SCLK cycles would have elapsed. At this stage, the ADC would be fully powered up and the signal acquired. So, in this case, the \overline{CS} can be brought high after the 10th SCLK falling edge and brought low again after a time, t_{QUIET} , to initiate the conversion.

When power supplies are first applied to the AD7441/AD7451, the ADC may either power up in the power-down mode or normal mode. Because of this, it is best to allow a dummy cycle to elapse to ensure that the part is fully powered up before attempting a valid conversion. Likewise, if the user wants the part to power up in power-down mode, then the dummy cycle may be used to ensure the device is in power-down mode by executing a cycle such as that shown in Figure 15. Once supplies are applied to the AD7441/AD7451, the power-up time is the same as that when powering up from power-down mode. It takes approximately 1 μ s to power up fully if the part powers up in normal mode. It is not necessary to wait 1 μ s before executing a dummy cycle to ensure the desired mode of operation. Instead, the dummy cycle can occur directly after power is supplied to the ADC. If the first valid conversion is then performed directly after the dummy conversion, care must be taken to ensure that adequate acquisition time has been allowed.

As mentioned earlier, when powering up from the power-down mode, the part will return to track mode upon the first SCLK edge applied after the falling edge of \overline{CS} . However, when the ADC powers up initially after supplies are applied, the track-and-hold will already be in track mode. This means (assuming one has the facility to monitor the ADC supply current) that if the ADC powers up in the desired mode of operation and thus a dummy cycle is not required to change mode, then neither is a dummy cycle required to place the track-and-hold into track.

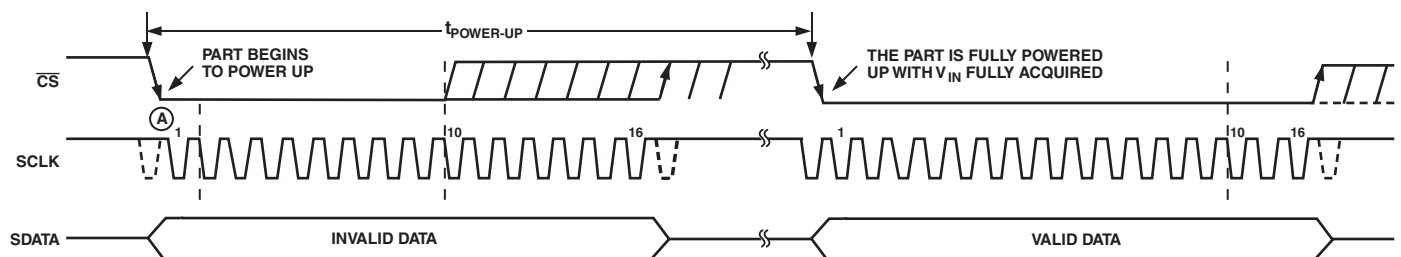


Figure 16. Exiting Power-Down Mode

AD7441/AD7451

POWER VS. THROUGHPUT RATE

By using the power-down mode on the AD7441/AD7451 when not converting, the average power consumption of the ADC decreases at lower throughput rates. Figure 17 shows how, as the throughput rate is reduced, the device remains in its power-down state longer and the average power consumption reduces accordingly. For example, if the AD7441/AD7451 is operated in continuous sampling mode with a throughput rate of 100 kSPS and an SCLK of 18 MHz, and the device is placed in the power-down mode between conversions, then the power consumption is calculated as follows:

Power dissipation during normal operation = 9.25 mW max (for $V_{DD} = 5\text{ V}$). If the power-up time is one dummy cycle, i.e., 1 μs , and the remaining conversion time is another cycle, i.e., 1 μs , then the AD7441/AD7451 can be said to dissipate 9.25 mW for 2 μs * during each conversion cycle.

If the throughput rate = 100 kSPS, then the cycle time = 10 μs and the average power dissipated during each cycle is

$$(2/10) \times 9.25\text{ mW} = 1.85\text{ mW}$$

For the same scenario, if $V_{DD} = 3\text{ V}$, the power dissipation during normal operation is 4 mW max.

The AD7441/AD7451 can now be said to dissipate 4 mW for 2 μs * during each conversion cycle.

The average power dissipated during each cycle with a throughput rate of 100 kSPS is therefore

$$(2/10) \times 4\text{ mW} = 0.8\text{ mW}$$

This is how the power numbers in Figure 17 are calculated.

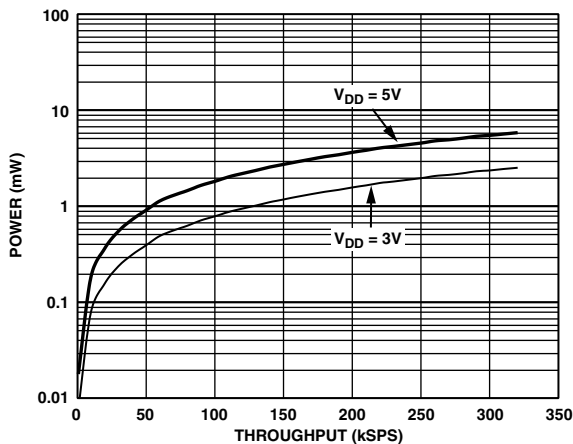


Figure 17. Power vs. Throughput Rate for Power-Down Mode

For throughput rates above 320 kSPS, it is recommended that for optimum power performance, the serial clock frequency is reduced.

*This figure assumes a very short time to enter power-down mode. This will increase as the burst of clocks used to enter the power down mode is increased.

MICROPROCESSOR AND DSP INTERFACING

The serial interface on the AD7441/AD7451 allows the part to be connected directly to a range of different microprocessors. This section explains how to interface the AD7441/AD7451 with some of the more common microcontroller and DSP serial interface protocols.

AD7441/AD7451 to ADSP-21xx

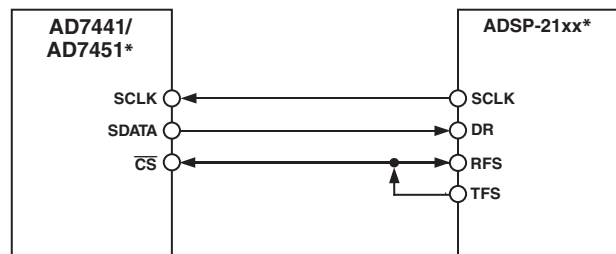
The ADSP-21xx family of DSPs are interfaced directly to the AD7441/AD7451 without any glue logic required.

The SPORT control register should be set up as follows:

TFSW = RFSW = 1	Alternate Framing
INVRFS = INVTFS = 1	Active Low Frame Signal
DTYPE = 00	Right Justify Data
SLEN = 1111	16-Bit Data Words
ISCLK = 1	Internal Serial Clock
TFSR = RFSR = 1	Frame Every Word
IRFS = 0	
ITFS = 1	

To implement the power-down mode, SLEN should be set to 1001 to issue an 8-bit SCLK burst.

The connection diagram is shown in Figure 18. The ADSP-21xx has the TFS and RFS of the SPORT tied together, with TFS set as an output and RFS set as an input. The DSP operates in alternate framing mode and the SPORT control register is set up as described. The frame synchronization signal generated on the TFS is tied to $\overline{\text{CS}}$, and, as with all signal processing applications, equidistant sampling is necessary. However, in this example, the timer interrupt is used to control the sampling rate of the ADC, and, under certain conditions, equidistant sampling may not be achieved.



*ADDITIONAL PINS REMOVED FOR CLARITY

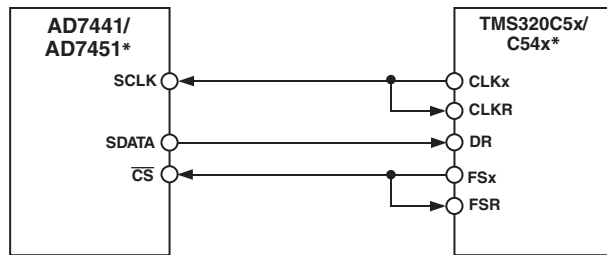
Figure 18. Interfacing to the ADSP-21xx

The timer registers, etc., are loaded with a value that will provide an interrupt at the required sample interval. When an interrupt is received, a value is transmitted with TFS/DT (ADC control word). The TFS is used to control the RFS and therefore the reading of data. The frequency of the serial clock is set in the SCLKDIV register. When the instruction to transmit with TFS is given, (i.e., AX0 = TX0), the state of the SCLK is checked. The DSP will wait until the SCLK has gone high, low, and high before transmission will start. If the timer and SCLK values are chosen such that the instruction to transmit occurs on or near the rising edge of SCLK, then the data may be transmitted or it may wait until the next clock edge.

For example, the ADSP-2111 has a master clock frequency of 16 MHz. If the SCLKDIV register is loaded with the value 3, then an SCLK of 2 MHz is obtained, and eight master clock periods will elapse for every 1 SCLK period. If the timer registers are loaded with the value 803, then 100.5 SCLKs will occur between interrupts and subsequently between transmit instructions. This situation will result in non-equidistant sampling as the transmit instruction is occurring on an SCLK edge. If the number of SCLKs between interrupts is a whole integer figure of N, then equidistant sampling will be implemented by the DSP.

AD7441/AD7451 to TMS320C5x/C54x

The serial interface on the TMS320C5x/C54x uses a continuous serial clock and frame synchronization signals to synchronize the data transfer operations with peripheral devices like the AD7441/AD7451. The \overline{CS} input allows easy interfacing between the TMS320C5x/C54x and the AD7441/AD7451 without any glue logic required. The serial port of the TMS320C5x/C54x is set up to operate in burst mode with internal CLKX (Tx serial clock) and FSX (Tx frame sync). The serial port control register (SPC) must have the following setup: FO = 0, FSM = 1, MCM = 1 and TXM = 1. The format bit, FO, may be set to 1 to set the word length to 8 bits in order to implement the power-down mode on the AD7441/AD7451. The connection diagram is shown in Figure 19. It should be noted that for signal processing applications, it is imperative that the frame synchronization signal from the TMS320C5x/C54x provide equidistant sampling.

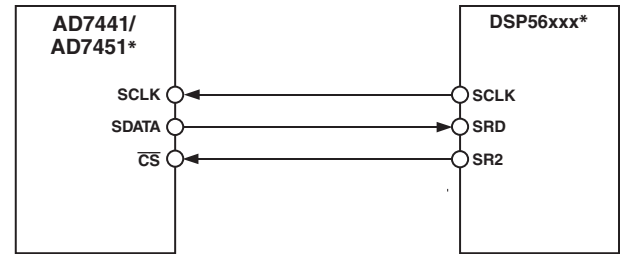


*ADDITIONAL PINS REMOVED FOR CLARITY

Figure 19. Interfacing to the TMS320C5x/C54x

AD7441/AD7451 to DSP56xxx

The connection diagram in Figure 20 shows how the AD7441/AD7451 can be connected to the SSI (synchronous serial interface) of the DSP56xxx family of DSPs from Motorola. The SSI is operated in synchronous mode (SYN bit in CRB = 1) with internally generated 1-bit clock period frame sync for both Tx and Rx (Bit FSL1 = 1 and Bit FSL0 = 0 in CRB). Set the word length to 16 by setting bits WL1 = 1 and WL0 = 0 in CRA. To implement the power-down mode on the AD7441/AD7451 the word length can be changed to eight bits by setting bits WL1 = 0 and WL0 = 0 in CRA. It should be noted that for signal processing applications, it is imperative that the frame synchronization signal from the DSP56xxx provide equidistant sampling.



*ADDITIONAL PINS REMOVED FOR CLARITY

Figure 20. Interfacing to the DSP56xxx

APPLICATION HINTS

Grounding and Layout

The printed circuit board that houses the AD7441/AD7451 should be designed so that the analog and digital sections are separated and confined to certain areas of the board. This facilitates the use of ground planes that can be easily separated. A minimum etch technique is generally best for ground planes as it gives the best shielding. Digital and analog ground planes should be joined in only one place, and the connection should be a star ground point established as close to the GND pin on the AD7441/AD7451 as possible.

Avoid running digital lines under the device as this will couple noise onto the die. The analog ground plane should be allowed to run under the AD7441/AD7451 to avoid noise coupling. The power supply lines to the AD7441/AD7451 should use as large a trace as possible to provide low impedance paths and reduce the effects of glitches on the power supply line.

Fast switching signals like clocks should be shielded with digital ground to avoid radiating noise to other sections of the board, and clock signals should never run near the analog inputs. Avoid crossover of digital and analog signals. Traces on opposite sides of the board should run at right angles to each other. This will reduce the effects of feedthrough through the board. A microstrip technique is by far the best but is not always possible with a double-sided board.

In this technique the component side of the board is dedicated to ground planes while signals are placed on the solder side. Good decoupling is also important. All analog supplies should be decoupled with 10 μ F tantalum capacitors in parallel with 0.1 μ F capacitors to GND. To achieve the best from these decoupling components, they must be placed as close as possible to the device.

EVALUATING THE AD7441/AD7451 PERFORMANCE

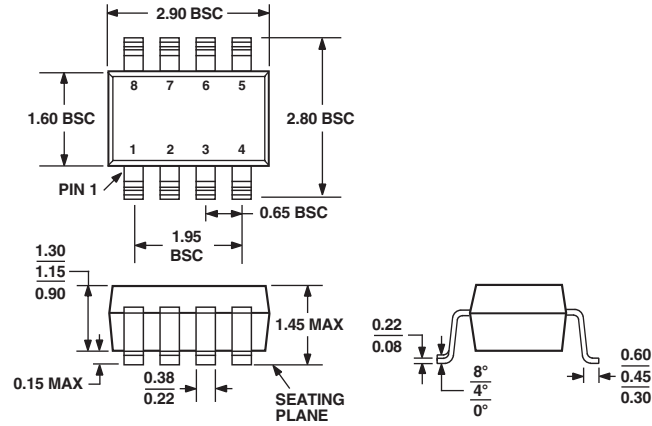
The Evaluation Board Package includes a fully assembled and tested evaluation board, documentation, and software for controlling the board from a PC via the evaluation board controller. The evaluation board controller can be used in conjunction with the AD7441 and the AD7451 evaluation boards, as well as many other Analog Devices evaluation boards ending with the CB designator, to demonstrate/evaluate the ac and dc performance of the AD7441 and the AD7451.

The software allows the user to perform ac (Fast Fourier Transform) and dc (histogram of codes) tests on the AD7441/AD7451. See the evaluation board application note for more information.

OUTLINE DIMENSIONS

8-Lead Small Outline Transistor Package [SOT-23] (RT-8)

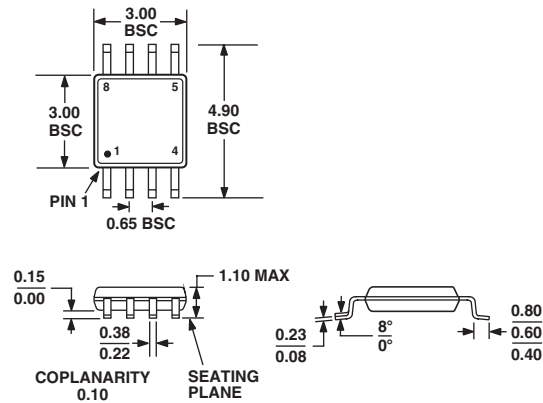
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-178BA

8-Lead Mini Small Outline Package [MSOP] (RM-8)

Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-187AA

